

TPS62864/6 2.4-V to 5.5-V Input, 4-A and 6-A Synchronous Step-Down Converter with I²C Interface in WCSP Package

1 Features

- 7-m Ω and 6.5-m Ω internal power MOSFETs
- >90% efficiency (0.9-V output)
- DCS-control topology for fast transient response
- 1% output voltage accuracy
- 4-µA operating quiescent current
- 2.4-V to 5.5-V input voltage range
- 2.4-MHz switching frequency
- · Selection by external resistor
- Start-up output voltage
 - I²C slave address
- Selection by I²C interface
 - Power save mode or forced PWM mode
 - Output discharge
 - Hiccup or latching short-circuit protection
 - Output voltage ramp speed
- VID pin for dynamic voltage scaling (DVS)
- Thermal pre-warning and thermal shutdown
- · Power good indicator pin option
- I²C-compatible interface up to 3.4 Mbps
- Available in 1.05-mm x 1.78-mm x 0.5-mm 15-pin WCSP package with 0.35-mm pitch
- Create a custom design using the TPS62866 with the WEBENCH® Power Designer

2 Applications

- Core supply for FPGAs, CPUs, ASICs or video chipsets
- Camera modules
- Solid-state drives
- Optical modules

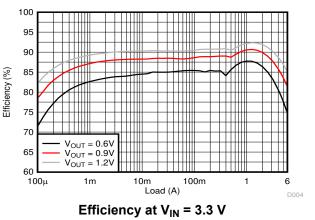
3 Description

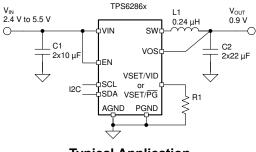
The TPS62864 and TPS62866 devices are highfrequency synchronous step-down converters with I²C interface which provide an efficient, adaptive, and high power-density solution. At medium to heavy loads, the converter operates in PWM mode and automatically enters Power Save Mode operation at light load to maintain high efficiency over the entire load current range. The device can also be forced in PWM mode operation for smallest output voltage ripple. Together with its DCS-control architecture, excellent load transient performance and tight output voltage accuracy are achieved. Via the I²C interface and a dedicated VID pin, the output voltage is quickly adjusted to adapt the power consumption of the load to the ever-changing performance needs of the application.

Device Information

PART NUMBER	PACKAGE ⁽¹⁾	BODY SIZE (NOM)		
TPS62864	WCSP (15)	1.05 x 1.78 x 0.5 mm		
TPS62866	WC3F (13)	1.03 × 1.76 × 0.3 mm		

(1) For all available packages, see the orderable addendum at the end of the data sheet.





Typical Application



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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision B (March 2020) to Revision C (October 2020)	Page
Removed instances of QFN package	1
• Updated the numbering format for tables, figures and cross-references the	nroughout the document1
Updated Device Options	
Removed Power Good (PG) section	
Updated I ² C Register Reset section	17
Changes from Revision A (December 2019) to Revision B (March 2020)	Page
Updated Figure 9-12	23
Changes from Revision * (June 2019) to Revision A (December 2019)	Page
Change device status from Advance Information to Production Data	1



5 Device Options

PART NUMBER ⁽¹⁾	START-UP OUTPUT VOLTAGE	OUTPUT CURRENT	
TPS62864 0A YCG		4.6	VID
TPS62864 0B YCG	0.4 V to 1.15 V, Selectable	4 A	PG
TPS62866 0A YCG		6 A	VID
TPS62866 0B YCG		0 A	PG

(1) For all available packages, see the orderable addendum at the end of the data sheet.

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6 Pin Configuration and Functions

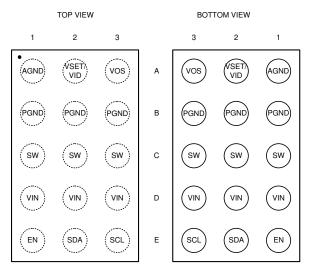


Figure 6-1. YCG (15 Pin)

Table 6-1. Pin Functions

PIN		DESCRIPTION
NAME	NO.	DESCRIPTION
AGND	A1	Analog ground pin
VSET/VID	A2	Start-up output voltage and device address selection pin. An external resistor must be connected. After start-up, the pin can be used to select the V_{OUT} registers for the output voltage. (Low = V_{OUT} register 1; High = V_{OUT} register 2). See Section 8.4.4.
VSET/PGA2Start-up output voltage and device address selection pin. An external resistor must be connected start-up, the pin is used for the power good indicator. When the output voltage is not regulated, to is driven high. When the output voltage is regulated, the pin is pulled low through the external resistor The function after start-up depends on the device option. See Section 5.		
VOS	A3	Output voltage sense pin. This pin must be directly connected to the output capacitor.
PGND	B1,B2,B3	Power ground pin
SW	C1,C2,C3	Switch pin of the power stage
VIN	D1,D2,D3	Power supply input voltage pin
EN E1 Device enable pin. To enable the device, this pin needs to be pulled high. Pulling t the device. Do not leave floating.		Device enable pin. To enable the device, this pin needs to be pulled high. Pulling this pin low disables the device. Do not leave floating.
SDA	E2	I ² C serial data pin. Do not leave it floating. Connect it to AGND if not used.
SCL	E3	I ² C serial clock pin. Do not leave it floating. Connect it to AGND if not used.



7 Specifications

7.1 Absolute Maximum Ratings

		MIN	MAX	UNIT
	VIN, EN, SDA, SCL, VOS, VSET/VID, VSET/PG	-0.3	6	
Voltage ⁽¹⁾	SW (DC)	-0.3	V _{IN} + 0.3	V
	SW (AC, less than 10ns) ⁽²⁾	-2.5	10	
I _{SOURCE_PG}	Source current at VSET/PG		1	mA
ISINK_SDA,SCL	Sink current at SDA, SCL		2	mA
TJ	Junction temperature	-40	150	°C
T _{stg}	Storage temperature	-65	150	°C

(1) All voltage values are with respect to network ground terminal.

(2) While switching.

7.2 ESD Ratings

			VALUE	UNIT
		Human body model (HBM), per ANSI/ESDA/ JEDEC JS-001, all pins ⁽¹⁾	±2000	M
V _(ESD)	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾	±500	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

		MIN	NOM MAX	UNIT
V _{IN}	Input voltage	2.4	5.5	V
t _{F_VIN}	Falling transition time at VIN ⁽¹⁾		10	mV/μs
I _{OUT}	Output current, TPS62864 ⁽²⁾	0	4	۸
	Output current, TPS62866 (3)	0	6	A
TJ	Junction temperature	-40	125	°C

(1) The falling slew rate of V_{IN} should be limited if V_{IN} goes below $V_{\text{UVLO}}.$

(2) Lifetime is reduced when operating continuously at 4-A output current and the junction temperature is higher than 105 °C.

(3) Lifetime is reduced when operating continuously at 6-A output current and the junction temperature is higher than 85 °C.

7.4 Thermal Information

		TPS62	86x YCG	
	THERMAL METRIC ⁽¹⁾	JEDEC 51-7	TPS62866EVM-051	UNIT
		15 PINS	15 PINS	
R _{0JA}	Junction-to-ambient thermal resistance	91.8	56.5	°C/W
R _{0JC(top)}	Junction-to-case (top) thermal resistance	0.8	n/a ⁽²⁾	°C/W
R _{θJB}	Junction-to-board thermal resistance	23.5	n/a ⁽²⁾	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	0.4	0.4	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	23.3	27.3	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

(2) Not applicable to an EVM.



7.5 Electrical Characteristics

 T_J = -40 °C to 125 °C, and V_{IN} = 2.4 V to 5.5 V. Typical values are at T_J = 25 °C and V_{IN} = 5 V, unless otherwise noted.

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
SUPPLY						
l _Q	Quiescent current	EN = High, no load, device not switching		4	10	μA
I _{SD}	Shutdown current	EN = Low, T_J = -40°C to 85°C		0.1	1	μA
	Under voltage lock out threshold	V _{IN} rising	2.2	2.3	2.4	V
V _{UVLO}	Onder voltage lock out threshold	V _{IN} falling	2.1	2.2	2.3	V
т	Thermal warning threshold	T _J rising		130		°C
T _{JW}	Thermal warning hysteresis	T _J falling		20		°C
Τ	Thermal shutdown threshold	T _J rising		150		°C
T _{JSD}	Thermal shutdown hysteresis	T _J falling		20		°C
LOGIC I	NTERFACE EN, SDA, SCL					
V _{IH}	High-level input threshold voltage at EN, SCL, SDA, VSET/VID		1.0			V
V _{IL}	Low-level input threshold voltage at EN, SCL, SDA, VSET/VID				0.4	V
I _{SCL,LKG}	Input leakage current into SCL pin			0.01	0.2	μA
I _{SDA,LKG}	Input leakage current into SDA pin			0.01	0.1	μA
I _{EN,LKG}	Input leakage current into EN pin			0.01	0.1	μA
C _{SCL}	Parasitic capacitance at SCL			1		pF
C _{SDA}	Parasitic capacitance at SCL			2.4		pF
STARTU	P, POWER GOOD	· · · · · ·				
t _{Delay}	Enable delay time	Time from EN high to device starts switching, R1 = $249k\Omega$	420	700	1100	μs
t _{Ramp}	Output voltage ramp time	Time from device starts switching to power good	0.9	1	1.5	ms
	Power good lower threshold	V _{VOS} referenced to V _{OUT} nominal	85	91	96	%
V _{PG}	Power good upper threshold	V _{VOS} referenced to V _{OUT} nominal	103	111	120	%
t _{PG,DLY}	Power good deglitch delay	Rising and falling edges		34		μs
OUTPUT	-					
	(1)	$V_{OUT} \ge 0.59 \text{ V}$, FPWM, no Load, $T_J = 25^{\circ}C$ to $125^{\circ}C$	-1		1	%
V _{OUT}	Output voltage accuracy ⁽¹⁾	V_{OUT} < 0.59 V, FPWM, no Load, T _J = 25°C to 125°C	-2		2	%
		EN = High, V _{VOS} = 1.8 V		18		μA
I _{VOS,LKG}	Input leakage current into VOS pin	EN = Low, Output discharge disabled, V_{VOS} = 1.8 V		0.2	2.5	μA
R _{DIS}	Output discharge resistor at VOS pin			15		Ω
	Load regulation	V _{OUT} = 0.9 V, FPWM		0.04		%/A
POWER	SWITCH					
	High-side FET on-resistance			7		mΩ
R _{DS(on)}	Low-side FET on-resistance			6.5		mΩ
		TPS62864	5	5.5	6	Α
	High-side FET forward current limit	TPS62866	7	7.7	8.5	Α
I _{LIM}	· · · · · · · · · · · ·	TPS62864		4.5		Α
	Low-side FET forward current limit	TPS62866		6.5		А
	Low-side FET negative current limit	TPS62864, TPS62866		-3		Α



7.5 Electrical Characteristics (continued)

 T_J = -40 °C to 125 °C, and V_{IN} = 2.4 V to 5.5 V. Typical values are at T_J = 25 °C and V_{IN} = 5 V, unless otherwise noted.

PARAMETER		PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
	f _{SW}	PWM switching frequency	I _{OUT} = 1 A, V _{OUT} = 0.9 V		2.4		MHz	

(1) Exclude codes: 0x20 (560 mV), 0x40 (720 mV), 0x60 (880 mV), 0x80 (1040 mV), 0xC4 (1360 mV), 0xE0 (1520 mV).

7.6 I²C InterfaceTiming Characteristics

	PARAMETER	TEST CONDITIONS	MIN M	4X	UNIT
		Standard mode	1	00	kHz
		Fast mode	4	00	kHz
		Fast mode plus		1	MHz
f _(SCL)	SCL Clock Frequency	High-speed mode (write operation), $C_B - 100 \text{ pF}$ max		3.4	MHz
		High-speed mode (read operation), $C_B - 100 \text{ pF}$ max		3.4	MHz
		High-speed mode (write operation), $C_B - 400 \text{ pF}$ max		1.7	MHz
		High-speed mode (read operation), $C_B - 400 \text{ pF}$ max		1.7	MHz
		Standard mode	4.7		μs
t _{BUF}	Bus Free Time Between a STOP and START Condition	Fast mode	1.3		μs
		Fast mode plus	0.5		μs
		Standard mode	4		μs
	Hold Time (Repeated) START	Fast mode	600		ns
t _{HD} , t _{STA}	condition	Fast mode plus	260		ns
		High-speed mode	160		ns
		Standard mode	4.7		μs
		Fast mode	1.3		μs
LOW	LOW Period of the SCL Clock	Fast mode plus	0.5		μs
		High-speed mode, C _B – 100 pF max	160		ns
		High-speed mode, C _B – 400 pF max	320		ns
	HIGH Period of the SCL Clock	Standard mode	4		μs
		Fast mode	600		ns
t _{HIGH}		Fast mode plus	260		ns
		High-speed mode, C _B – 100 pF max	60		ns
		High-speed mode, C _B – 400 pF max	120		ns
		Standard mode	4.7		μs
	Setup Time for a Repeated START	Fast mode	600		ns
t _{SU} , t _{STA}	Condition	Fast mode plus	260		ns
		High-speed mode	160		ns
		Standard mode	250		ns
	Data Datas Tina	Fast mode	100		ns
t _{SU} , t _{DAT}	Data Setup Time	Fast mode plus	50		ns
		High-speed mode	10		ns
		Standard mode	0 3.	45	μs
		Fast mode	0	0.9	μs
t _{HD} , t _{DAT}	Data Hold Time	Fast mode plus	0		μs
		High-speed mode, C _B – 100 pF max	0	70	ns
		High-speed mode, C _B – 400 pF max	0 1	50	ns

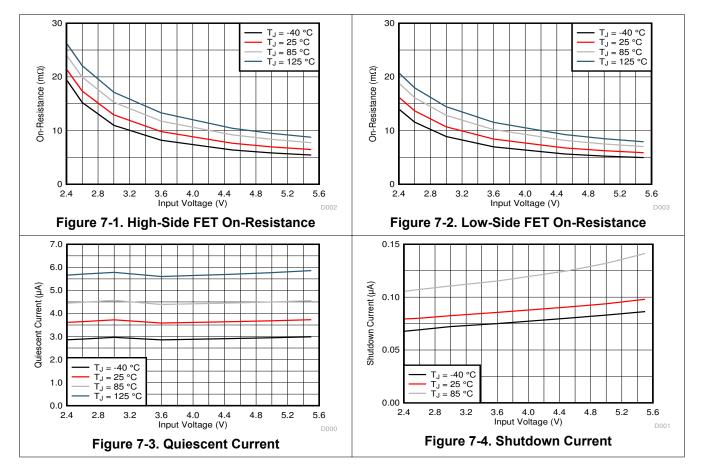
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	PARAMETER TEST CONDITIONS N			MAX	UNIT	
	Standard mode			1000	ns	
t:		Fast mode	20 + 0.1 C _B	300	ns	
RCL	Rise Time of SCL Signal	Fast mode plus		120	ns	
		High-speed mode, C _B – 100 pF max	10	40	ns	
		High-speed mode, C _B – 400 pF max	20	80	ns	
		Standard mode	20 + 0.1 C _B	1000	ns	
RCL1	Rise Time of SCL Signal After a Repeated START Condition and After	Fast mode	20 + 0.1 C _B	300	ns	
	an Acknowledge BIT	Fast mode plus		120	ns	
		High-speed mode, C _B – 100 pF max	10	80	ns	
		High-speed mode, C _B – 400 pF max	20	160	ns	
		Standard mode	20 + 0.1 C _B	300	ns	
	Fall Time of SCL Signal	Fast mode		300	ns	
FCL		Fast mode plus		120	ns	
		High-speed mode, C _B – 100 pF max	10	40	ns	
		High-speed mode, C _B – 400 pF max	20	80	ns	
		Standard mode		1000	ns	
	Rise Time of SDA Signal	Fast mode	20 + 0.1 C _B	300	ns	
RDA		Fast mode plus		120	ns	
		High-speed mode, C _B – 100 pF max	10	80	ns	
		High-speed mode, C _B – 400 pF max	20	160	ns	
		Standard mode		300	ns	
		Fast mode	20 + 0.1 C _B	300	ns	
FDA	Fall Time of SDA Signal	Fast mode plus		120	ns	
		High-speed mode, C _B – 100 pF max	10	80	ns	
		High-speed mode, C _B – 400 pF max	20	160	ns	
		Standard mode	4		μs	
f	Setup Time of STOP Condition	Fast mode	600		ns	
t _{SU,} t _{STO}		Fast mode plus	260		ns	
		High-Speed mode	160		ns	
		Standard mode		400	pF	
C _	Capacitive Load for SDA and SCL	Fast mode		400	pF	
C _B	Capacitive Load for SDA and SCL	Fast mode plus		550	pF	
		High-Speed mode		400	pF	



7.7 Typical Characteristics





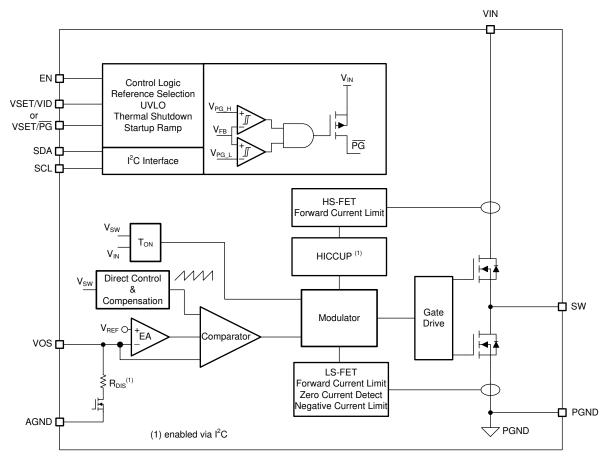
8 Detailed Description

8.1 Overview

The TPS62864 and TPS62866 synchronous step-down converters use the DCS-Control (Direct Control with Seamless transition into Power Save Mode) topology. This is an advanced regulation topology that combines the advantages of hysteretic and current-mode control schemes.

The DCS-Control[™] topology operates in PWM (pulse width modulation) mode for medium to heavy load conditions and in Power Save Mode at light load currents. In PWM mode, the converter operates with its nominal switching frequency of 2.4 MHz, having a controlled frequency variation over the input voltage range. Because DCS-Control supports both operation modes (PWM and PFM) within a single building block, the transition from PWM mode to Power Save Mode is seamless without affecting the output voltage. The devices offer both excellent DC voltage and superior load transient regulation, combined with very low output voltage ripple.

8.2 Functional Block Diagram



8.3 Feature Description

8.3.1 Power Save Mode

As the load current decreases, the device enters Power Save Mode (PSM) operation. PSM occurs when the inductor current becomes discontinuous, which is when it reaches 0 A during a switching cycle. Power Save Mode is based on a fixed on-time architecture, as shown in Equation 1.

$$t_{ON} = \frac{V_{OUT}}{V_{IN}} \cdot 416 \text{ns}$$

(1)



In Power Save Mode, the output voltage rises slightly above the nominal output voltage. This effect is minimized by increasing the output capacitor or inductor value.

8.3.2 Forced PWM Mode

With I²C, set the device in forced PWM (FPWM) mode by the CONTROL register. The device switches at 2.4 MHz, even with a light load. This reduces the output voltage ripple and allows simple filtering of the switching frequency for noise-sensitive applications. Efficiency at light load is lower in FPWM mode.

8.3.3 Start-up

After enabling the device, there is an enable delay (t_{Delay}) before the device starts switching. During this period, the device sets the internal reference voltage, and determines the start-up output voltage through the resistor connected to the VSET/VID or VSET/ \overline{PG} pin. After t_{delay} , all registers can be read and written by the I²C interface.

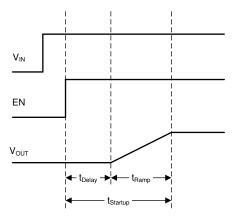


Figure 8-1. Start-up Sequence

After the enable delay, an internal soft start-up circuitry ramps up the output voltage with a period of 1 ms (t_{Ramp}). This avoids excessive inrush current and creates a smooth output voltage rising-slope. It also prevents excessive voltage drops of primary cells and rechargeable batteries with high internal impedance.

The device is able to start into a pre-biased output capacitor. It starts with the applied bias voltage and ramps the output voltage to its nominal value.

8.3.4 Switch Current Limit and HICCUP Short-Circuit Protection

The switch current limit prevents the device from high inductor current and drawing excessive current from the battery or input voltage rail. Excessive current can occur with a shorted or saturated inductor or a heavy load or shorted output circuit condition. If the inductor current reaches the threshold I_{LIM} , cycle by cycle, the high-side MOSFET is turned off and the low-side MOSFET is turned on, while the inductor current ramps down to the low-side MOSFET current limit.

When the high-side MOSFET current limit is triggered 32 times, the device stops switching. The device then automatically re-starts, with an internal soft start-up, after a typical delay time of 128 µs has passed. This is named HICCUP short-circuit protection. The device repeats this mode until the high load condition disappears.

The HICCUP is disabled by the CONTROL register bit Enable HICCUP. Disabling HICCUP changes the overcurrent protection to latching protection. The device stops switching after the high-side MOSFET current limit is triggered 32 times. Toggling the EN pin, removing and reapplying the input voltage, or writing to the CONTROL register bit Software Enable Device unlatches the device.

8.3.5 Undervoltage Lockout (UVLO)

To avoid mis-operation of the device at low input voltages, undervoltage lockout (UVLO) is implemented when the input voltage is lower than V_{UVLO} . The device stops switching and the output voltage discharge is active (if



enabled through I²C) when the device is in UVLO. When the input voltage recovers, the device automatically returns to operation with an internal soft start-up. During UVLO, the internal register values are kept.

The UVLO bit in the STATUS Register is set when the input voltage is less than the UVLO falling threshold. When the input voltage is below 1.8 V (typ), all registers are reset.

8.3.6 Thermal Warning and Shutdown

When the junction temperature goes up to T_{JW} , the device gives a pre-warning indicator in the STATUS register. The device keeps running.

When the junction temperature exceeds T_{JSD} , the device goes into thermal shutdown, stops switching, and activates the output voltage discharge. When the device temperature falls below the threshold by 20°C, the device returns to normal operation automatically with an internal soft start-up. During thermal shutdown, the internal register values are kept.

8.4 Device Functional Modes

8.4.1 Enable and Disable (EN)

The device is enabled by setting the EN pin to a logic High. In shutdown mode (EN = Low), the internal power switches as well as the entire control circuitry are turned off, and all the registers are reset, except for the Enable Output Discharge bit. Do not leave the EN pin floating.

In shutdown mode (EN = Low), all registers cannot be read and written by the I²C interface.

The typical threshold value of the EN pin is 0.61 V for rising input signals, and 0.51 V for falling input signals.

The device is also enabled or disabled by setting the bit, Software Enable Device in CONTROL register while EN = High. After being disabled/enabled by this bit, the device stops switching and has a new start-up beginning with t_{Ramp} . There is no T_{Delay} time and the registers are not reset.

8.4.2 Output Discharge

An internal MOSFET switch smoothly discharges the output through the VOS pin in shutdown mode (EN = Low or Software Enable Device bit = 0). The output discharge is also active when the device is in thermal shutdown and UVLO.

When the Enable Output Discharge bit is set to 0, the output discharge function is disabled. The input voltage must remain higher than 1 V (TYP) to keep the output discharge function operational and the status of the Enable Output Discharge bit retained. The Enable Output Discharge bit is reset on the rising edge of the EN pin.

8.4.3 Start-up Output Voltage and I²C Slave Address Selection (VSET)

During the enable delay (t_{Delay}), the start-up output voltage and device I²C slave address are set by an external resistor connected to the VSET/VID or VSET/ \overline{PG} pin through an internal R2D (resistor to digital) converter. Table 8-1 shows the options.

RESISTOR (E96 SERIES, ±1% ACCURACY) AT VSET/VID OR VSET/ PG	START-UP OUTPUT VOLTAGE (TYP)	I ² C SLAVE ADDRESS
249 kΩ	1.15 V	1000 110
205 kΩ	1.10 V	1000 101
162 kΩ	1.05 V	1000 100
133 kΩ	1.00 V	1000 011
105 kΩ	0.95 V	1000 010
86.6 kΩ	0.90 V	1000 001
68.1 kΩ	0.85 V	1001 000
56.2 kΩ	0.80 V	1001 001
44.2 kΩ	0.75 V	1001 010
36.5 kΩ	0.70 V	1001 011

Table 8-1. Start-up Output Voltage and I²C Slave Address Options

Table 6-1. Start-up Output Voltage and TC Slave Address Options (continued)								
RESISTOR (E96 SERIES, ±1% ACCURACY) AT VSET/VID OR VSET/ PG	START-UP OUTPUT VOLTAGE (TYP)	I ² C SLAVE ADDRESS						
28.7 kΩ	0.65 V	1001 100						
23.7 kΩ	0.60 V	1001 101						
18.7 kΩ	0.55 V	1001 110						
15.4 kΩ	0.50 V	1001 111						
12.1 kΩ	0.45 V	1000 000						
10 kΩ	0.40 V	1000 111						

Table 8-1. Start-up Output Voltage and I²C Slave Address Options (continued)

The R2D converter has an internal current source which applies current through the external resistor, and an internal ADC which reads back the resulting voltage level. Depending on the level, the correct start-up output voltage and I²C slave address are set. Once this R2D conversion is finished, the current source is turned off to avoid current flowing through the external resistor. Ensure that there is no additional current path or capacitance greater than 30 pF from this pin to GND during R2D conversion. Otherwise a false value is set.

During the ramp up period (t_{Ramp}), the output voltage ramps to the target value set by VSET first, then ramps up or down to the new value when the value of the output register is changed by I^2C interface commands.

8.4.4 Select Output Voltage Registers (VID)

After the start-up period ($t_{Startup}$), the output voltage can be selected between two output voltage registers by the VID pin. When VID is pulled low, the output voltage is set by Table 8-4. When VID is pulled high, the output voltage is set by Table 8-5. This is also called dynamic voltage scaling (DVS).

During an output voltage change through I²C or the VSET/VID pin, the device can be set in FPWM by the Enable FPWM Mode during Output Voltage Change bit in CONTROL register. The output voltage change speed is set by the Voltage Ramp Speed bit.

8.4.5 Power Good (PG)

The TPS62864 and TPS62864 families provide device options with the VSET/ PG pin, instead of a VSET/VID pin, shown in Figure 9-1.

After the enable delay (t_{Delay}), the device starts to compare the output voltage with the nominal value set by the external resistor or the output voltage registers. Table 8-2 shows the logic level of the \overline{PG} pin. The pin is driven up to the input voltage for a logic high. The pin is pulled down to GND by the external resistor R1 for a logic low.

For the VSET/ \overline{PG} option devices, be aware of the following:

- VSET/ PG can not be connected to GND. A resistor, R1, must be connected between VSET/ PG and GND, for the start-up output voltage and I²C slave address setup.
- The source current of the VSET/ \overline{PG} pin is up to 1 mA.
- V_{OUT} Register 2 is disabled.
- When the device is in shutdown, the shutdown current is high because of the leakage current through the external resistor, R1, when the VSET/ PG pin is high.

The VSET/ \overline{PG} has a deglitch time, before the signal goes high or low, during normal operation. For start-up, the VSET/ \overline{PG} has a delay time of 200 µs after the output voltage reaches the nominal voltage.

	DEVICE CONDITIONS	PG LOGIC STATUS			
	Device conditions	HIGH	LOW		
Enable	$0.91 \text{ x V}_{\text{OUT}_{\text{NOM}}} \le V_{\text{VOS}} \le 1.11 \text{ x V}_{\text{OUT}_{\text{NOM}}}$				
Enable	V_{VOS} < 0.91 x V_{OUT_NOM} or V_{VOS} > 1.11 x V_{OUT_NOM}	√			
Shutdown	EN = Low	√			
Thermal Shutdown	$T_{J} > T_{JSD}$	√			
UVLO	$1.8 \text{ V} < \text{V}_{\text{IN}} < \text{V}_{\text{UVLO}}$	√			

Table 8-	2. VSET	7 PG Pin	Logic
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Table 8-2. VSET/ PG Pin Logic (continued)

DEVICE CONDITIONS		STATUS
Device conditions	HIGH	LOW
Power Supply Removal V _{IN} < 1.8 V	unde	fined

8.5 Programming

8.5.1 Serial Interface Description

I²C is a 2-wire serial interface developed by Philips Semiconductor, now NXP Semiconductors. The bus consists of a data line (SDA) and a clock line (SCL) with pullup structures. When the bus is *idle*, both SDA and SCL lines are pulled high. All the I²C compatible devices connect to the I²C bus through open drain I/O pins, SDA and SCL. A *master* device, usually a microcontroller or a digital signal processor, controls the bus. The master is responsible for generating the SCL signal and device addresses. The master also generates specific conditions that indicate the START and STOP of data transfer. A *slave* device receives or transmits data on the bus under control of the master device, or both.

The device works as a *slave* and supports the following data transfer *modes*, as defined in the I²C-Bus Specification: standard mode (100 kbps) and fast mode (400 kbps), fast mode plus (1 Mbps) and high-speed mode (3.4 Mbps). The interface adds flexibility to the power supply solution, enabling most functions to be programmed to new values depending on the instantaneous application requirements. Register contents remain intact as long as the input voltage remains above 1.8 V.

The data transfer protocol for standard and fast modes is exactly the same, therefore, they are referred to as F/S-mode in this document. The protocol for high-speed mode is different from F/S-mode, and it is referred to as HS-mode.

It is recommended that the I^2C master initiates a STOP condition on the I^2C bus after the initial power up of SDA and SCL pullup voltages to ensure reset of the I^2C engine.

8.5.2 Standard-, Fast-, and Fast-Mode Plus Protocol

The master initiates data transfer by generating a start condition. The start condition is when a high-to-low transition occurs on the SDA line while SCL is high, as shown in Figure 8-2. All I²C-compatible devices recognize a start condition.

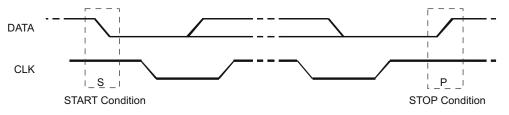


Figure 8-2. START and STOP Conditions

The master then generates the SCL pulses, and transmits the 7-bit address and the read/write direction bit R/W on the SDA line. During all transmissions, the master ensures that data is valid. A valid data condition requires the SDA line to be stable during the entire high period of the clock pulse (see Figure 8-3). All devices recognize the address sent by the master and compare it to their internal fixed addresses. Only the slave device with a matching address generates an acknowledge (see Figure 8-4) by pulling the SDA line low during the entire high period of the ninth SCL cycle. Upon detecting this acknowledge, the master knows that communication link with a slave has been established.



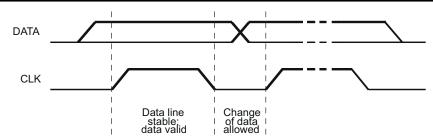


Figure 8-3. Bit Transfer on the Serial Interface

The master generates further SCL cycles to either transmit data to the slave (R/W bit 1) or receive data from the slave (R/W bit 0). In either case, the receiver needs to acknowledge the data sent by the transmitter. So an acknowledge signal can either be generated by the master or by the slave, depending on which one is the receiver. 9-bit valid data sequences consisting of 8-bit data and 1-bit acknowledge can continue as long as necessary.

To signal the end of the data transfer, the master generates a stop condition by pulling the SDA line from low to high while the SCL line is high (see Figure 8-2). This releases the bus and stops the communication link with the addressed slave. All I²C compatible devices must recognize the stop condition. Upon the receipt of a stop condition, all devices know that the bus is released, and they wait for a start condition followed by a matching address.

Attempting to read data from register addresses not listed in this section results in 00h being read out.

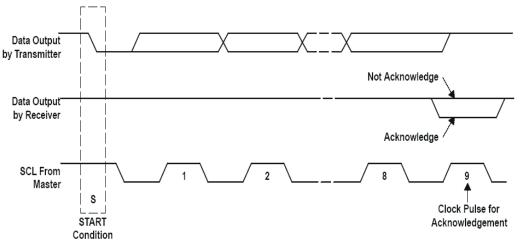


Figure 8-4. Acknowledge on the I²C Bus



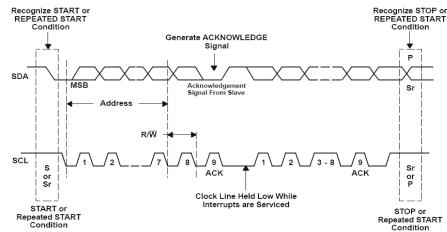


Figure 8-5. Bus Protocol

8.5.3 HS-Mode Protocol

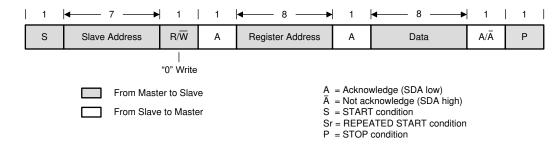
The master generates a start condition followed by a valid serial byte containing HS master code 00001XXX. This transmission is made in F/S-mode at no more than 400 Kbps. No device is allowed to acknowledge the HS master code, but all devices must recognize it and switch their internal setting to support 3.4 Mbps operation.

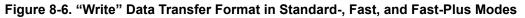
The master then generates a *repeated start condition* (a repeated start condition has the same timing as the start condition). After this repeated start condition, the protocol is the same as F/S-mode, except that transmission speeds up to 3.4 Mbps are allowed. A stop condition ends the HS-mode and switches all the internal settings of the slave devices to support the F/S-mode. Instead of using a stop condition, repeated start conditions must be used to secure the bus in HS-mode.

Attempting to read data from register addresses not listed in this section results in 00h being read out.

8.5.4 I²C Update Sequence

The sequence requires a start condition, a valid I^2C slave address, a register address byte, and a data byte for a single update. After the receipt of each byte, the device acknowledges by pulling the SDA line low during the high period of a single clock pulse. A valid I^2C address selects the device. The device performs an update on the falling edge of the acknowledge signal that follows the LSB byte.





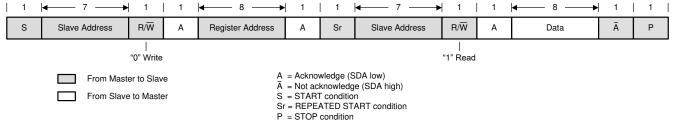


Figure 8-7. "Read" Data Transfer Format in Standard-, Fast, and Fast-Plus Modes



◀──── F/S Mode ─── 1 ◀─── 8 ───►	⊳ ⊲ 1 1 ⊲	7 1	1	HS Mode ↓ 8	1	₩ 8 →	1	▶ 1	<f mode<="" s="" th=""></f>
S HS-Master Code	Ā Sr	Slave Address R/W	А	Register Address	А	Data	A/Ā	Р	
From Slave to Master $S = S$				SDA low) ge (SDA high) n ART condition	Bytes +	Acknowledge) ————		✓ HSSr	Mode continues Slave Address

Figure 8-8. Data Transfer Format in HS-Mode

8.5.5 I²C Register Reset

The I²C registers can be reset by:

- Pulling the input voltage below 1.8 V (typ)
- A high to low transition on EN.
- Setting the Reset bit in the CONTROL register. When Reset is set to 1, all registers are reset to the default values and a new start-up is begun immediately. After t_{Delav}, the I²C registers can be programmed again.

8.6 Register Map

REGISTER ADDRESS (HEX)	REGISTER NAME	FACTORY DEFAULT (HEX)	DESCRIPTION						
0x01	V _{OUT} Register 1	0x64	Sets the target output voltage						
0x02	V _{OUT} Register 2	0x64	Sets the target output voltage						
0x03	CONTROL Register	0x6F	Sets miscellaneous configuration bits						
0x05	STATUS Register	0x00	Returns status flags						

Table 8-3. Register Map

8.6.1 Slave Address Byte

7	6	5	4	3	2	1	0
1	х	х	х	х	х	х	R/W

The slave address byte is the first byte received following the START condition from the master device. The slave addresses can be assigned by an external resistor, see Table 8-1.

8.6.2 Register Address Byte

7	6	5	4	3	2	1	0
0	0	0	0	0	D2	D1	D0

Following the successful acknowledgment of the slave address, the bus master sends a byte to the device, which contains the address of the register to be accessed.

8.6.3 V_{OUT} Register 1

REGISTER ADDRESS 0X01 READ/WRITE					
BIT	FIELD	VALUE (HEX)	OUTPUT VOLTAGE (TYP) ⁽¹⁾		
7:0 VC	VO1_SET	0x00	400 mV		
		0x01	405 mV		
		0x64	900 mV		



Table 8-4. V_{OUT} Register 1 Description (continued)

REGISTER ADDRESS 0X01 READ/WRITE						
BIT FIELD VALUE (HEX) OUTPUT VOLTAGE (TYP) ⁽¹⁾						
		0xFE	1670 mV			
		0xFF	1675 mV			

⁽¹⁾ It is not recommended to use the following codes, as their output voltage accuracy may have a wider tolerance than the specification: 0x20 (560 mV), 0x40 (720 mV), 0x60 (880 mV), 0x80 (1040 mV), 0xC4 (1360 mV), 0xE0 (1520 mV).

8.6.4 V_{OUT} Register 2

Table 8-5. V_{OUT} Register 2 Description

REGISTER ADDRESS 0X02 READ/WRITE					
BIT	FIELD	VALUE (HEX)	OUTPUT VOLTAGE (TYP) ⁽¹⁾		
7:0 VO2_SET	0x00	400 mV			
		0x01	405 mV		
	7:0 VO2_SET	0x64	900 mV (default value)		
		0xFE	1670 mV		
		0xFF	1675 mV		

(1) It is not recommended to use the following codes, as their output voltage accuracy may have a wider tolerance than the specification: 0x20 (560 mV), 0x40 (720 mV), 0x60 (880 mV), 0x80 (1040 mV), 0xC4 (1360 mV), 0xE0 (1520 mV).



8.6.5 CONTROL Register

Table 8-6. CONTROL Register Description

REGISTE	REGISTER ADDRESS 0X03 WRITE ONLY						
BIT	FIELD	TYPE	DEFAULT	DESCRIPTION			
7	Reset	R/W	0	1 - Reset all registers to default.			
6	Enable FPWM Mode during Output Voltage Change	R/W	1	0 - Keep the current mode status during output voltage change 1 - Force the device in FPWM during output voltage change			
5	Software Enable Device	R/W	1	 0 - Disable the device. All registers values are still kept. 1 - Re-enable the device with a new startup without the t_{Delay} period. 			
4	Enable FPWM Mode	R/W	0	0 - set the device in power save mode at light loads.1 - set the device in forced PWM mode at light loads.			
3	Enable Output Discharge	R/W	1	0 - Disable output discharge 1 - Enable output discharge			
2	Enable HICCUP	R/W	1	0 - Disable HICCUP. Enable latching protection. 1 - Enable HICCUP, Disable latching protection.			
0:1	Voltage Ramp Speed	R/W	11	00 - 20mV/μs (0.25 μs/step) 01 - 10 mV/μs (0.5 μs/step) 10 - 5 mV/μs (1 μs/step) 11 - 1 mV/μs (5 μs/step, default)			

8.6.6 STATUS Register

Table 8-7. STATUS Register Description

REGISTER	REGISTER ADDRESS 0X05 READ ONLY ⁽¹⁾					
BIT	FIELD	TYPE	DEFAULT	DESCRIPTION		
7:5	7:5 Reserved					
4	4 Thermal Warning 3 HICCUP		0	1: Junction temperature is higher than 130°C		
3			0	1: Device has HICCUP status once		
2	2 Reserved					
1	Reserved					
0	UVLO	R	0	1: The input voltage is less than UVLO threshold (falling edge)		

(1) All bit values are latched until the device is reset, or the STATUS register is read. Then, the STATUS register is reset to its default values.



9 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The following section discusses the design of the external components to complete the power supply design for several input and output voltage options by using typical applications as a reference.

9.2 Typical Applications

9.2.1 6-A Output Current Application

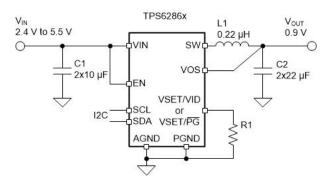


Figure 9-1. Typical Application

9.2.1.1 Design Requirements

For this design example, use the parameters listed in Table 9-1 as the input parameters.

Table 9-1. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE			
Input voltage	2.4 V to 5.5 V			
Output voltage	0.9 V			
Maximum output current	6 A			

Table 9-2 lists the components used for the example.

Table 9-2. List of Components of Figure 9-1

REFERENCE	DESCRIPTION	MANUFACTURER ⁽¹⁾			
C1	10 μF, Ceramic capacitor, 6.3 V, X7R, size 0603, CL10B106MQ8NRNC	Samsung Electro- Mechanics			
C2	22 μF, Ceramic capacitor, 6.3 V, X7R, size 0805, GRM21BZ70J226ME44L	Murata			
L1	0.22 μH, Power inductor, XAL4020-221ME (12 A, 5.81 mΩ)	Coilcraft			
R1	Depending on the start-up output voltage, size 0603	Std			

(1) See Third-party Products disclaimer.



9.2.1.2 Detailed Design Procedure

9.2.1.2.1 Custom Design With WEBENCH® Tools

Click here to create a custom design using the TPS62866 device with the WEBENCH® Power Designer.

- 1. Start by entering the input voltage (V_{IN}), output voltage (V_{OUT}), and output current (I_{OUT}) requirements.
- 2. Optimize the design for key parameters such as efficiency, footprint, and cost using the optimizer dial.
- 3. Compare the generated design with other possible solutions from Texas Instruments.

The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

In most cases, these actions are available:

- Run electrical simulations to see important waveforms and circuit performance
- · Run thermal simulations to understand board thermal performance
- · Export customized schematic and layout into popular CAD formats
- Print PDF reports for the design, and share the design with colleagues

Get more information about WEBENCH tools at www.ti.com/WEBENCH.

9.2.1.2.2 Setting The Output Voltage

The initial output voltage is set by an external resistor connected to the VSET/VID or VSET/ \overline{PG} pin, according to Table 8-1. After the soft start-up, the output voltage can be changed in the V_{OUT} Registers. Refer to Table 8-4 and Table 8-5.

9.2.1.2.3 Output Filter Design

The inductor and the output capacitor together provide a low-pass filter. To simplify this process, Table 9-3 outlines possible inductor and capacitor value combinations for most applications. Checked cells represent combinations that are proven for stability by simulation and lab test. Further combinations should be checked for each individual application.

Table 9-3. Matrix of Output Capacitor and Inductor Combinations

NOM	NOMINAL L [µH] ⁽²⁾	NOMINAL C _{OUT} [µF] ⁽³⁾				
		22	2 x 22 or 47	3 x 22	150	
	0.24		+(1)	+	+	

(1) This LC combination is the standard value and recommended for most applications.

(2) Inductor tolerance and current derating is anticipated. The effective inductance can vary by 20% and -30%.

(3) Capacitance tolerance and bias voltage derating is anticipated. The effective capacitance can vary by 20% and -30%.

9.2.1.2.4 Inductor Selection

The main parameter for the inductor selection is the inductor value and then the saturation current of the inductor. To calculate the maximum inductor current under static load conditions, Equation 2 is given.

$$I_{L,MAX} = I_{OUT,MAX} + \frac{\Delta I_L}{2}$$

$$\Delta I_{L} = V_{OUT} \times \frac{1 - \frac{V_{OUT}}{V_{IN}}}{L \times f_{SW}}$$

where

- I_{OUT,MAX} = maximum output current
- ΔI_L = inductor current ripple
- f_{SW} = switching frequency



L = inductor value

It is recommended to choose a saturation current for the inductor that is approximately 20% to 30% higher than $I_{L,MAX}$. In addition, DC resistance and size must also be taken into account when selecting an appropriate inductor. Table 9-4 lists recommended inductors.

INDUCTANCE [µH]	CURRENT RATING, I _{SAT} [A]	DIMENSIONS [L x W x H mm]	DC RESISTANCE [mΩ]	PART NUMBER ⁽¹⁾			
0.22	18.7	4 x 4 x 2	5.81	Coilcraft, XAL4020-221ME			
0.24	6.6	2 x 1.6 x 1.2	13	Murata, DFE201612E-R24M			

Table 9-4. List of Recommended Inductors

(1) See *Third-party Products* disclaimer.

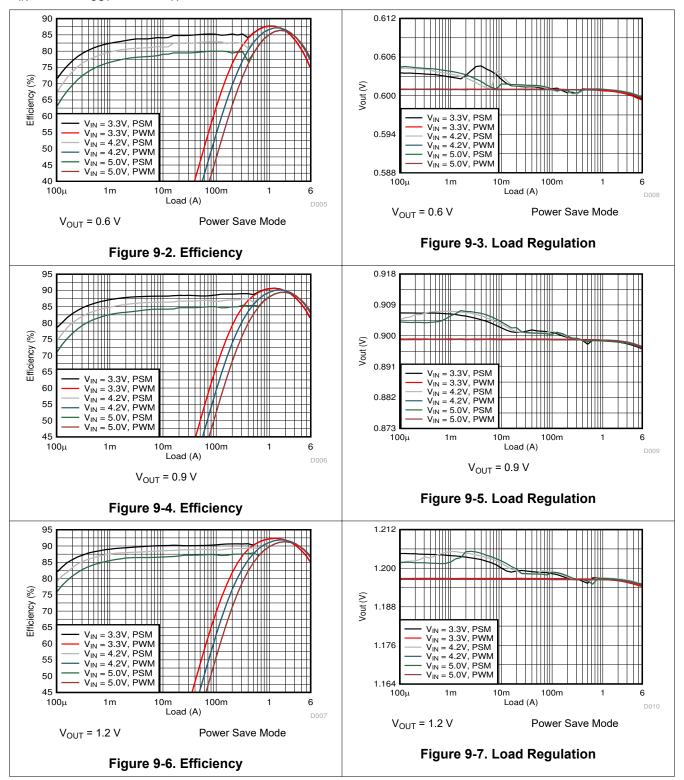
9.2.1.2.5 Capacitor Selection

The input capacitor is the low-impedance energy source for the converter which helps to provide stable operation. A low-ESR multilayer ceramic capacitor is recommended for best filtering and must be placed between VIN and PGND as close as possible to those pins. For most applications, 8 µF is a sufficient value for the effective input capacitance, though a larger value reduces input current ripple.

The architecture of the device allows the use of tiny ceramic output capacitors with low equivalent series resistance (ESR). These capacitors provide low output voltage ripple and are recommended. To keep its low resistance up to high frequencies and to get narrow capacitance variation with temperature, TI recommends using X7R or X5R dielectrics. The recommended minimum output effective capacitance is 30 μ F; this capacitance can vary over a wide range as outline in the output filter selection table.



9.2.1.3 Application Curves

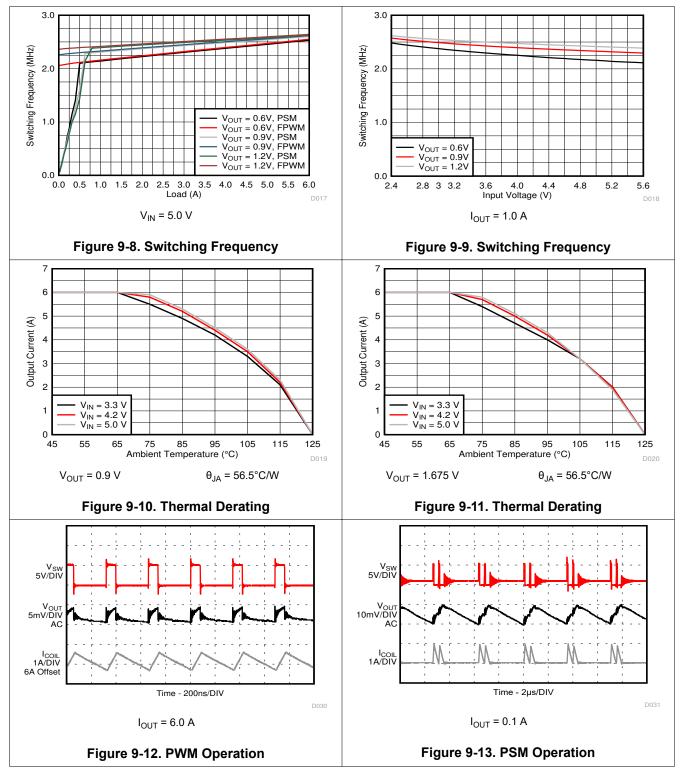


V_{IN} = 5.0 V, V_{OUT} = 0.9 V, T_A = 25°C, BOM = Table 9-2, unless otherwise noted.

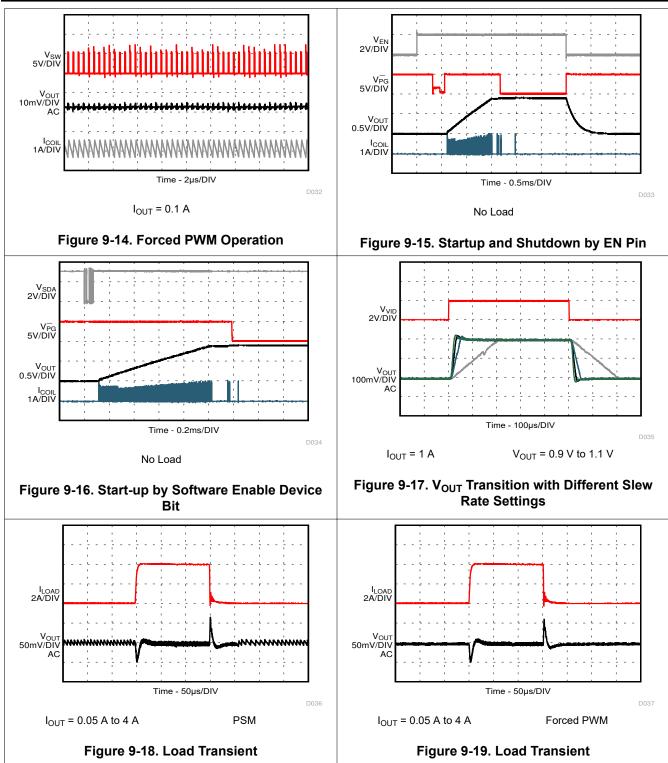
TPS62864, TPS62866

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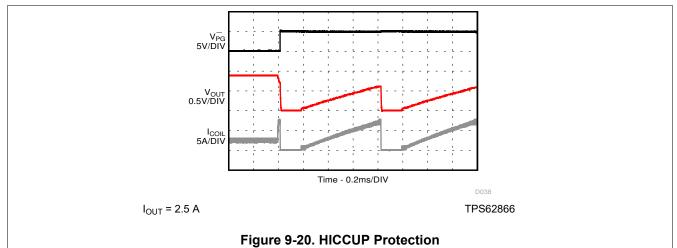












9.2.2 Smaller Application Solution

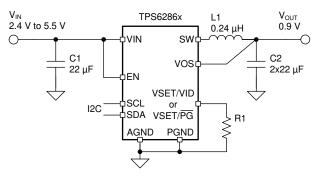


Figure 9-21. Smaller Application

9.2.2.1 Design Requirements

For this design, use the parameters listed in Table 9-5 as the input parameters. The design (Table 9-6) is optimized for the smallest solution size.

Table 9-5. Design Parameters					
DESIGN PARAMETER EXAMPLE VALUE					
Input voltage	3.3 V				
Output voltage	0.9 V				
Maximum output current	4 A				
Ambient temperature	25°C				

Table 9-5. Design Parameters

Table 9-6. List of Components of Table 9-5

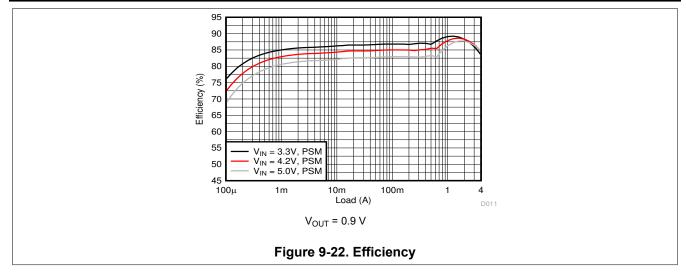
REFERENCE	DESCRIPTION	MANUFACTURER ⁽¹⁾
C1, C2	22 μF, Ceramic capacitor, 6.3 V, X5R, size 0402, GRM155R60J226ME11	Murata
L1	0.24 µH, Power inductor, size 0806, DFE201612E-R24M	Murata
R1	Depending on the startup output voltage, size 0402	Std

(1) See *Third-party Products* disclaimer.

9.2.2.2 Application Curves

 V_{IN} = 5.0 V, V_{OUT} = 0.9 V, T_A = 25°C, BOM = Table 9-6, unless otherwise noted.





10 Power Supply Recommendations

The device is designed to operate from an input voltage supply range from 2.4 V to 5.5 V. Ensure that the input power supply has a sufficient current rating for the application. The power supply must avoid a fast ramp down. The falling ramp speed must be slower than 10 mV/ μ s, if the input voltage drops below V_{UVLO}.



11 Layout

11.1 Layout Guidelines

The printed-circuit-board (PCB) layout is an important step to maintain the high performance of the device.

- The input/output capacitors and the inductor must be placed as close as possible to the IC. This keeps the power traces short. Routing these power traces direct and wide results in low trace resistance and low parasitic inductance.
- The low side of the input and output capacitors must be connected properly to the PGND to avoid a GND potential shift.
- The sense traces connected to the VOS pin is a signal trace. Special care must be taken to avoid noise being induced. Keep the trace away from SW.
- Refer to Figure 11-1 for an example of component placement, routing, and thermal design.

11.2 Layout Example

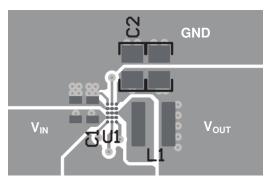


Figure 11-1. Layout Example

11.3 Thermal Considerations

Implementation of integrated circuits in low-profile and fine-pitch surface-mount packages typically requires special attention to power dissipation. Many system-dependent issues such as thermal coupling, airflow, added heat sinks and convection surfaces, and the presence of other heat-generating components affect the power dissipation limits of a given component.

Two basic approaches for enhancing thermal performance are improving the power dissipation capability of the PCB design and introducing airflow in the system. For more details on how to use the thermal parameters, see the *Semiconductor and IC Package Thermal Metrics Application Report*.



12 Device and Documentation Support

12.1 Device Support

12.1.1 Third-Party Products Disclaimer

TI'S PUBLICATION OF INFORMATION REGARDING THIRD-PARTY PRODUCTS OR SERVICES DOES NOT CONSTITUTE AN ENDORSEMENT REGARDING THE SUITABILITY OF SUCH PRODUCTS OR SERVICES OR A WARRANTY, REPRESENTATION OR ENDORSEMENT OF SUCH PRODUCTS OR SERVICES, EITHER ALONE OR IN COMBINATION WITH ANY TI PRODUCT OR SERVICE.

12.2 Documentation Support

12.2.1 Related Documentation

For related documentation, see the following:

Texas Instruments, Semiconductor and IC Package Thermal Metrics Application Report

12.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

12.4 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.5 Trademarks

DCS-Control[™] is a trademark of TI. TI E2E[™] is a trademark of Texas Instruments. All other trademarks are the property of their respective owners.

12.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.7 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

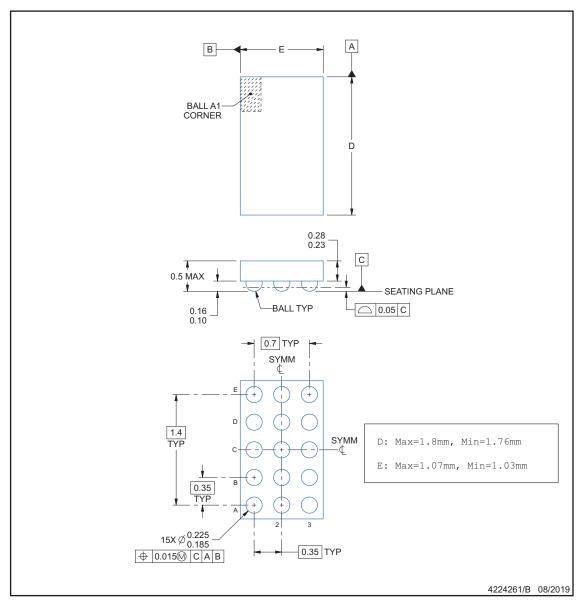
YCG0015



PACKAGE OUTLINE

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing

per ASME Y14.5M.2. This drawing is subject to change without notice.



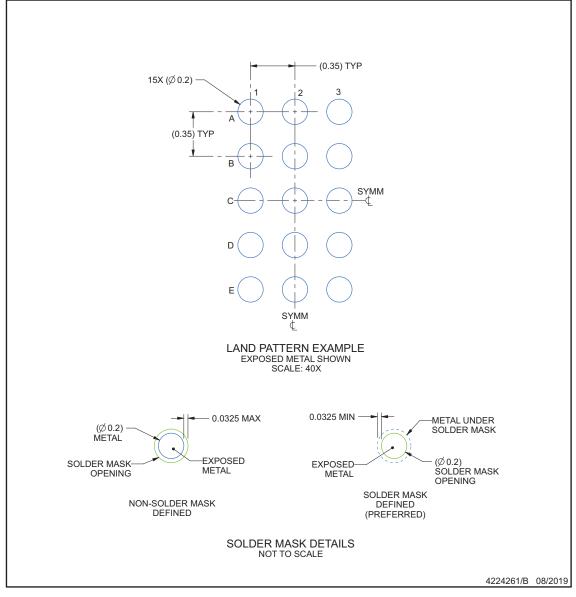


YCG0015

EXAMPLE BOARD LAYOUT

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES: (continued)

3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. See Texas Instruments Literature No. SNVA009 (www.ti.com/lit/snva009).



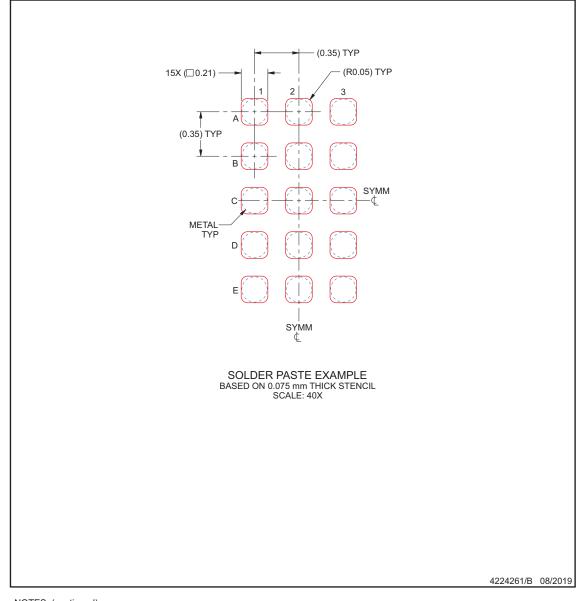
YCG0015



EXAMPLE STENCIL DESIGN

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.





PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
TPS628640AYCGR	Active	Production	DSBGA (YCG) 15	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	8640A
TPS628640AYCGR.A	Active	Production	DSBGA (YCG) 15	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	8640A
TPS628640BYCGR	Active	Production	DSBGA (YCG) 15	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	8640B
TPS628640BYCGR.A	Active	Production	DSBGA (YCG) 15	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	8640B
TPS628660AYCGR	Active	Production	DSBGA (YCG) 15	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	8660A
TPS628660AYCGR.A	Active	Production	DSBGA (YCG) 15	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	8660A
TPS628660BYCGR	Active	Production	DSBGA (YCG) 15	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	8660B
TPS628660BYCGR.A	Active	Production	DSBGA (YCG) 15	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	8660B

⁽¹⁾ Status: For more details on status, see our product life cycle.

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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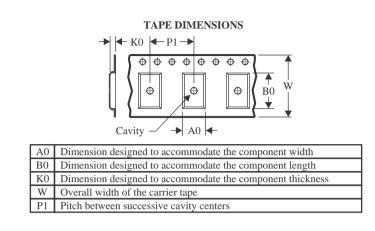
Texas

*All dimensions are nominal

STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS628640AYCGR	DSBGA	YCG	15	3000	180.0	8.4	1.22	1.95	0.6	4.0	8.0	Q1
TPS628640BYCGR	DSBGA	YCG	15	3000	180.0	8.4	1.22	1.95	0.6	4.0	8.0	Q1
TPS628660AYCGR	DSBGA	YCG	15	3000	180.0	8.4	1.22	1.95	0.6	4.0	8.0	Q1
TPS628660BYCGR	DSBGA	YCG	15	3000	180.0	8.4	1.22	1.95	0.6	4.0	8.0	Q1



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PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS628640AYCGR	DSBGA	YCG	15	3000	182.0	182.0	20.0
TPS628640BYCGR	DSBGA	YCG	15	3000	182.0	182.0	20.0
TPS628660AYCGR	DSBGA	YCG	15	3000	182.0	182.0	20.0
TPS628660BYCGR	DSBGA	YCG	15	3000	182.0	182.0	20.0

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